NSN 5962-01-155-1503

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-155-1503

Body Length:

0.440 inches

Body Width:

Between 0.245 inches and 0.285 inches

Body Height:

Between 0.045 inches and 0.085 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and programmable and bipolar

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Case Outline Source And Designator:

F-5 mil-m-38510

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

97942-583r971 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 flat leads

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

Yes - demil/mli

NSN 5962-01-155-1503

Memory Microcircuit - Page 2 of 2

Fiig: A458a0

